

VLMS334.., VLMR334.., VLMK334.., VLMY334..

Vishay Semiconductors

Power SMD LED PLCC-2



DESCRIPTION

The VLM.334.. series is an advanced modification of the Vishay VLM.31.. series. It is designed to incorporate larger chips, therefore, capable of withstanding a 70 mA drive current.

The package of the VLM.334.. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-2
- Product series: power
- Angle of half intensity: ± 60°

PARTS TABLE

FEATURES

- Utilizing latest advanced AlInGaP technology
- Available in 8 mm tape
- Luminous intensity and color categorized per packing unit
- Luminous intensity ratio per packing unit $I_{Vmax.}/I_{Vmin.} \leq 1.6$
- Thermal resistance R = 300 K/W
- ESD-withstand voltage: Up to 2 kV according to JESD22-A114-B
- Preconditioning according to JEDEC[®] level 2a
- Compatible with reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Traffic signals and signs
- Interior and exterior lighting
- Dashboard illumination
- Indicator and backlighting purposes for audio, video, LCDs switches, symbols, illuminated advertising etc.

PARTS TABLE																
PART	COLOR	LUMINOUS INTENSITY (mcd)		INTENSITY		ITENSITY		WA	VELEN (nm)	GTH	at I _F (mA)		ORWAF OLTAG (V)		at I _F (mA)	TECHNOLOGY
		MIN.	TYP.	MAX.	(mA)	MIN.	TYP.	MAX.	(IIIA)	MIN.	TYP.	MAX.	(IIIA)			
VLMS334AABB-GS08	Super red	1120	1600	2800	50	626	630	639	50	1.9	2.2	2.8	50	AllnGaP on Si		
VLMS334AABB-GS18	Super red	1120	1600	2800	50	626	630	639	50	1.9	2.2	2.8	50	AllnGaP on Si		
VLMR334BACB-GS08	Red	1800	2200	4500	50	619	625	631	50	1.9	2.2	2.8	50	AllnGaP on Si		
VLMR334BACB-GS18	Red	1800	2200	4500	50	619	625	631	50	1.9	2.2	2.8	50	AllnGaP on Si		
VLMK334BACB-GS08	Amber	1800	2800	4500	50	611	616	622	50	1.9	2.25	2.8	50	AllnGaP on Si		
VLMK334BACB-GS18	Amber	1800	2800	4500	50	611	616	622	50	1.9	2.25	2.8	50	AllnGaP on Si		
VLMY334BACB-GS08	Yellow	1800	2300	4500	50	583	589	594	50	1.9	2.3	2.8	50	AllnGaP on Si		
VLMY334BACB-GS18	Yellow	1800	2300	4500	50	583	589	594	50	1.9	2.3	2.8	50	AllnGaP on Si		

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified) **VLMS334..., VLMR334..., VLMK334..., VLMY334...**

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage ⁽¹⁾	Short term application only	V _R	5	V	
DC forward current	T _{amb} ≤ 65 °C (300 K/W)	I _F	70	mA	
Surge forward current	t _p ≤ 10 μs	I _{FSM}	0.1	A	
Power dissipation		Pv	200	mW	
Junction temperature		Тj	125	°C	
Operating temperature range		T _{amb}	-40 to +100	°C	
Storage temperature range		T _{stg}	-40 to +100	°C	
Thermal resistance junction-to-ambient	Mounted on PC board (pad size > 16 mm ²)	R _{thJA}	300	K/W	

Note

⁽¹⁾ Driving the LED in reverse direction is suitable for a short term application

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COMPLIANT HALOGEN FREE GREEN (5-2008)



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OPTICAL AND ELECTRIC VLMS334, SUPER RED	AL CHARACTER	ISTICS (T _{amb} =	25 °C, unl	ess other	wise spec	cified)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 50 mA	VLMS334AABB	Ι _V	1120	1600	2800	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	I _F = 50 mA		λ_d	626	630	639	nm
Peak wavelength	I _F = 50 mA		λρ	-	639	-	nm
Spectral bandwidth at 50 % Irel max.	I _F = 50 mA		Δλ	-	18	-	nm
Angle of half intensity	I _F = 50 mA		φ	-	± 60	-	0
Forward voltage	I _F = 50 mA		V _F	1.9	2.2	2.8	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μA

OPTICAL AND ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified) **VLMR334.., RED**

VENINGST, NED							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 50 mA	VLMR334BACB	Ι _V	1800	2200	4500	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	I _F = 50 mA		λ _d	619	625	631	nm
Peak wavelength	I _F = 50 mA		λρ	-	632	-	nm
Spectral bandwidth at 50 % Irel max.	I _F = 50 mA		Δλ	-	18	-	nm
Angle of half intensity	I _F = 50 mA		φ	-	± 60	-	0
Forward voltage	I _F = 50 mA		V _F	1.9	2.2	2.8	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μA

OPTICAL AND ELECTRICAL CHARACTERISTICS (T $_{amb}$ = 25 °C, unless otherwise specified) VLMK334.., AMBER

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 50 mA	VLMK334BACB	Ιv	1800	2800	4500	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	I _F = 50 mA		λ_d	611	616	622	nm
Peak wavelength	$I_F = 50 \text{ mA}$		λρ	-	622	-	nm
Spectral bandwidth at 50 % I _{rel max.}	I _F = 50 mA		Δλ	-	18	-	nm
Angle of half intensity	I _F = 50 mA		φ	-	± 60	-	0
Forward voltage	I _F = 50 mA		V _F	1.9	2.25	2.8	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μA

OPTICAL AND ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified) **VLMY334..., YELLOW**

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PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 50 mA	VLMY334BACB	Ι _V	1800	2300	4500	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	I _F = 50 mA		λ_d	583	589	594	nm
Peak wavelength	I _F = 50 mA		λρ	-	591	-	nm
Spectral bandwidth at 50 % I _{rel max.}	I _F = 50 mA		Δλ	-	17	-	nm
Angle of half intensity	I _F = 50 mA		φ	-	± 60	-	0
Forward voltage	I _F = 50 mA		V _F	1.9	2.3	2.8	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μA



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		DOM. WAVELENGTH (nm)					
GROUP	AM	AMBER		W			
	MIN.	MAX.	MIN.	MAX.			
1	611	618	-	-			
2	614	622	583	586			
3	-	-	585	588			
4	-	-	587	590			
5	-	-	589	592			
6	-	-	591	594			

Note

· Wavelengths are tested at a current pulse duration of 25 ms

LUMINOUS INTENSITY CLASSIFICATION						
GROUP	LIGHT INTENSITY (mcd)					
STANDARD	MIN.	MAX.				
AA	1120	1400				
AB	1400	1800				
BA	1800	2240				
BB	2240	2800				
CA	2800	3550				
СВ	3550	4500				

Note

 Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

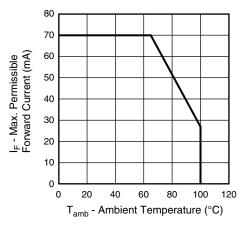
The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable







CROSSING TABLE						
OSRAM						
LS T67F-T2V2-1-1						
LR T67F-U1AA-1-1						
LA T67F-U2AB-24-1						
LY T67F-U1AA-36-1						

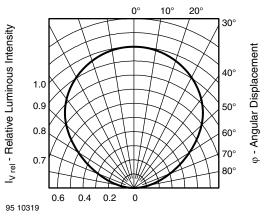


Fig. 2 - Relative Luminous Intensity vs. Angular Displacement

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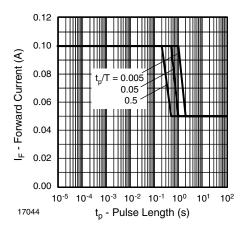


Fig. 3 - Forward Current vs. Pulse Length

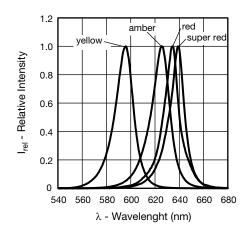


Fig. 4 - Relative Intensity vs. Wavelength

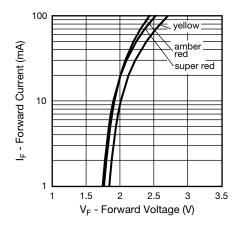


Fig. 5 - Forward Current vs. Forward Voltage

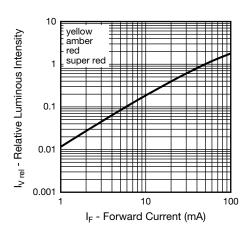


Fig. 6 - Relative Luminous Intensity vs. Forward Current

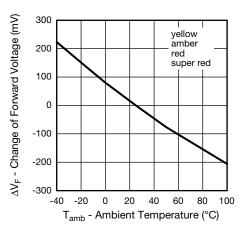


Fig. 7 - Change of Forward Voltage vs. Ambient Temperature

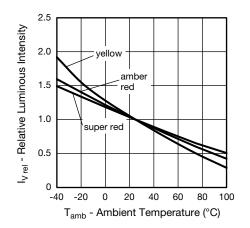


Fig. 8 - Relative Luminous Intensity vs. Ambient Temperature

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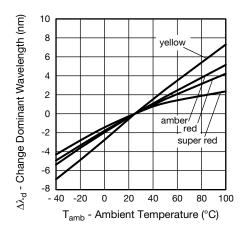
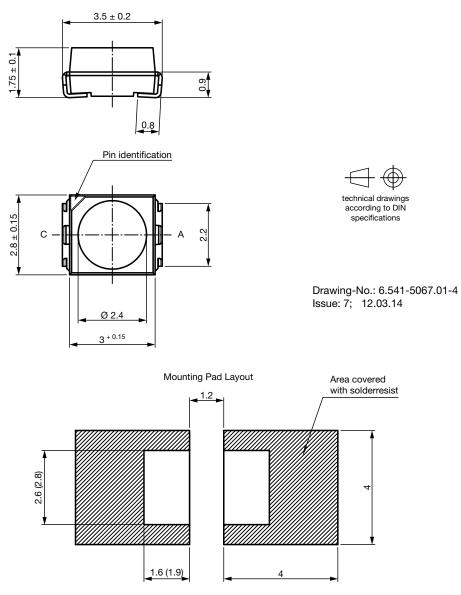


Fig. 9 - Change of Dominant Wavelength vs. Ambient Temperature



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PACKAGE DIMENSIONS in millimeters



Dimensions: reflow and vapor phase (wave soldering)



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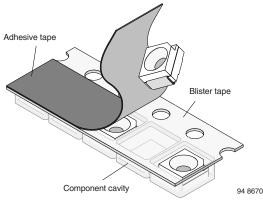
METHOD OF TAPING / POLARITY AND TAPE AND REEL

SMD LED (VLMx334..-SERIES)

www.vishay.com

ISHAY

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



TAPING OF VLMx334...

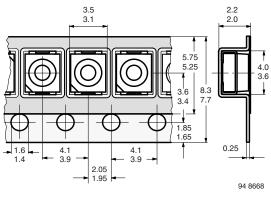


Fig. 10 - Tape Dimensions in mm for PLCC-2

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

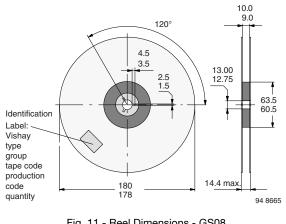


Fig. 11 - Reel Dimensions - GS08

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REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED

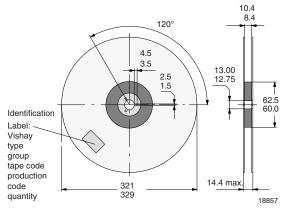


Fig. 12 - Reel Dimensions - GS18

SOLDERING PROFILE

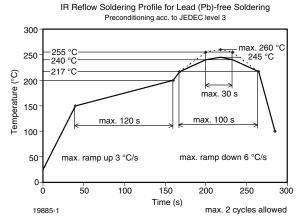


Fig. 13 - Vishay Lead (Pb)-free Reflow Soldering Profile (according to J-STD-020)

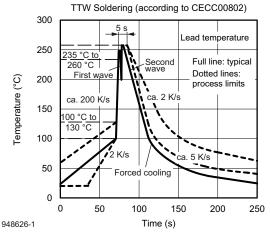


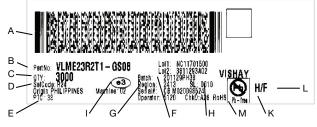
Fig. 14 - Double Wave Soldering of Opto Devices (all Packages)

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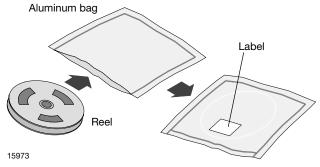
BAR CODE PRODUCT LABEL (example only)



- A. 2D barcode
- B. Vishay part number
- C. Quantity
- D. PTC = selection code (binning)
- E. Code of manufacturing plant
- F. Batch = date code: year/week/plant code
- G. Region code
- H. SL = sales location
- I. Terminations finishing
- K. Lead (Pb)-free symbol
- L. Halogen-free symbol
- M.RoHS symbol

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

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RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity \leq 60 % RH max.

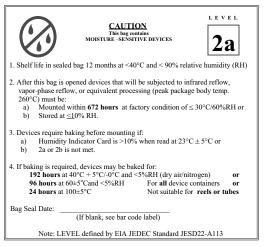
After more than 672 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition: 192 h at 40 °C + 5 °C / - 0 °C and < 5 % RH (dry air/nitrogen)

or 96 h at 60 $^{\circ}\text{C}$ + 5 $^{\circ}\text{C}$ and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electrostatic sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABEL

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

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